MOSFET - Power, Single N-Channel, STD Gate, SO8-FL

40 V, 0.42 mΩ, 509 A

NVMFWS0D4N04XM

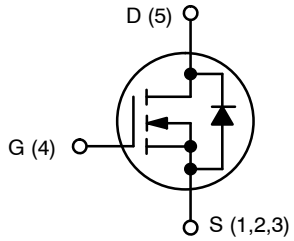
$V_{(BR)DSS}$	$R_{DS(on)}$ MAX	I_D MAX
40 V	0.42 mΩ @ 10 V	509 A

Features

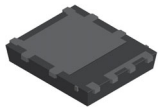
- Low $R_{DS(on)}$ to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- Small Footprint (5x6 mm) with Compact Design
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Motor Drive
- Battery Protection
- Synchronous Rectification

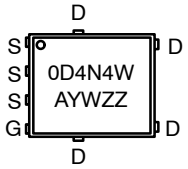


N-CHANNEL MOSFET



DFNW5 (SO-8FL WF)
CASE 507BD

MARKING DIAGRAM



A = Assembly Location
Y = Year
W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 2 of this data sheet.

MAXIMUM RATINGS (T_J = 25 °C unless otherwise stated)

Parameter		Symbol	Value	Unit
Drain-to-Source Voltage		V_{DSS}	40	V
Gate-to-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	T_C = 25 °C	I_D	509	A
	T_C = 100 °C		360	
Power Dissipation	T_C = 25 °C	P_D	197	W
Pulsed Drain Current	T_A = 25 °C, t_p = 10 μs	I_{DM}	900	A
Pulsed Source Current (Body Diode)		I_{SM}	900	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	−55 to +175	°C
Source Current (Body Diode)		I_S	311	A
Single Pulse Avalanche Energy	I_{PK} = 38.6 A	E_{AS}	2396	mJ
Lead Temperature for Soldering Purposes (1/8″ from case for 10 s)		T_L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case (Note 2)	$R_{\theta JC}$	0.76	°C/W
Thermal Resistance, Junction-to-Ambient (Notes 1, 2)	$R_{\theta JA}$	38.2	

1. Surface-mounted on FR4 board using 650 mm^2, 2 oz Cu pad.
2. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

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ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0 V, I_D = 250 μA, T_J = 25 °C	40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	$\Delta V_{(BR)DSS}/\Delta T_J$	I_D = 250 μA, Referenced to 25 °C		14.9		mV/°C
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 40 V, T_J = 25 °C			1	μA
		V_{DS} = 40 V, T_J = 125 °C			80	
Gate-to-Source Leakage Current	I_{GSS}	V_{GS} = 20 V, V_{DS} = 0 V			100	nA
ON CHARACTERISTICS						
Drain-to-Source On Resistance	$R_{DS(ON)}$	V_{GS} = 10 V, I_D = 50 A, T_J = 25 °C		0.33	0.42	mΩ
Gate Threshold Voltage	$V_{GS(TH)}$	V_{GS} = V_{DS}, I_D = 330 μA, T_J = 25 °C	2.5	3	3.5	V
Gate Threshold Voltage Temperature Coefficient	$\Delta V_{GS(TH)}/\Delta T_J$	V_{GS} = V_{DS}, I_D = 330 μA		−7.21		mV/°C
Forward Trans-conductance	g_{FS}	V_{DS} = 5 V, I_D = 50 A		286		S
CHARGES, CAPACITANCES & GATE RESISTANCE						
Input Capacitance	C_{ISS}	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz		8530		pF
Output Capacitance	C_{OSS}			5451		
Reverse Transfer Capacitance	C_{RSS}			72		
Total Gate Charge	$Q_{G(TOT)}$	V_{DD} = 32 V, I_D = 50 A, V_{GS} = 10 V		132		nC
Threshold Gate Charge	$Q_{G(TH)}$			24.9		
Gate-to-Source Charge	Q_{GS}			37.2		
Gate-to-Drain Charge	Q_{GD}			23.7		
Gate Resistance	R_G	f = 1 MHz		0.42		Ω
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	$t_{d(ON)}$	Resistive Load, V_{GS} = 0/10 V, V_{DD} = 32 V, I_D = 50 A, R_G = 0 Ω		9.98		ns
Rise Time	t_r			5.49		
Turn-Off Delay Time	$t_{d(OFF)}$			15.5		
Fall Time	t_f			8.41		
SOURCE-TO-DRAIN DIODE CHARACTERISTICS						
Forward Diode Voltage	V_{SD}	I_S = 50 A, V_{GS} = 0 V, T_J = 25 °C		0.79	1.2	V
		I_S = 50 A, V_{GS} = 0 V, T_J = 125 °C		0.63		
Reverse Recovery Time	t_{RR}	V_{GS} = 0 V, I_S = 50 A, dI/dt = 100 A/μs, V_{DD} = 32 V		84		ns
Charge Time	t_a			46		
Discharge Time	t_b			38		
Reverse Recovery Charge	Q_{RR}			215		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping†
NVMFWS0D4N04XMT1G	0D4N4W	DFNW5 (Pb-Free)	1500 / Tape & Reel
NVMFWS0D4N04XMET1G	0D4N4W	DFNW5 (Pb-Free)	1500 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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TYPICAL CHARACTERISTICS

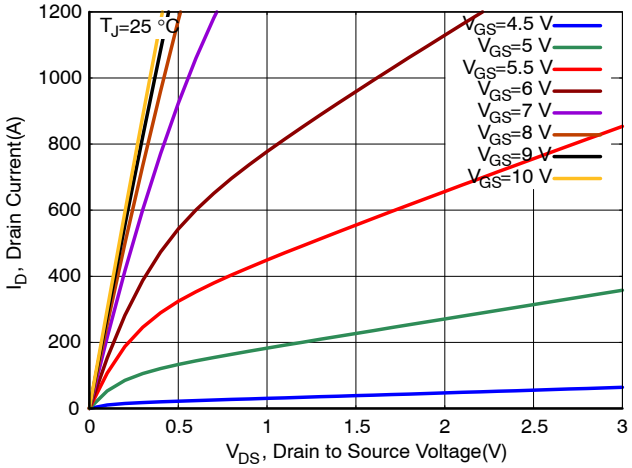


Figure 1. On−Region Characteristics

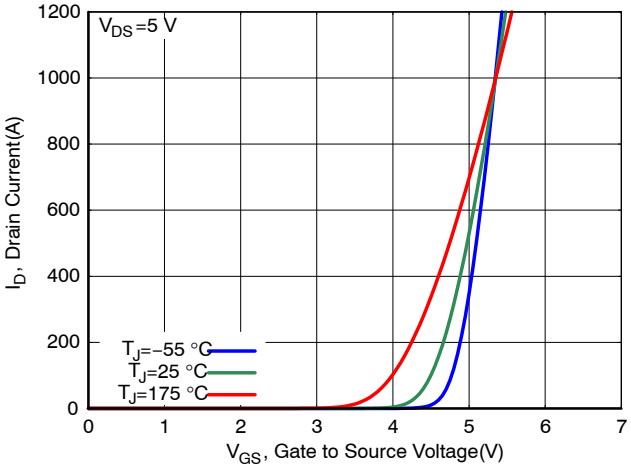


Figure 2. Transfer Characteristics

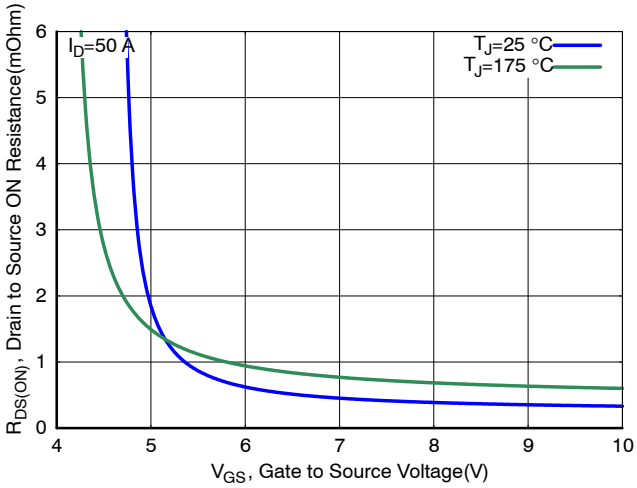


Figure 3. On−Resistance vs. Gate Voltage

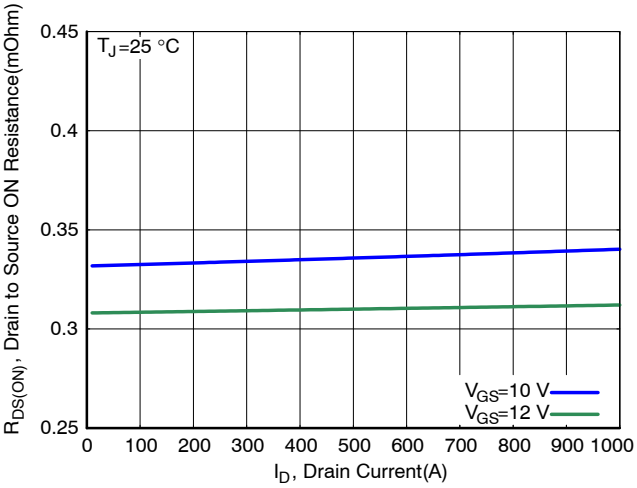


Figure 4. On−Resistance vs. Drain Current

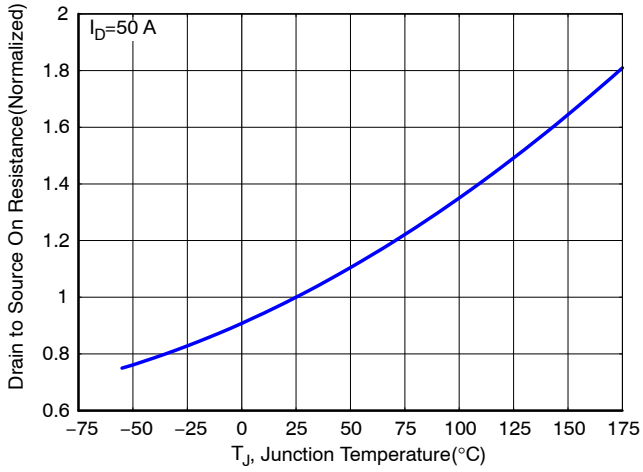


Figure 5. Normalized ON Resistance vs. Junction Temperature

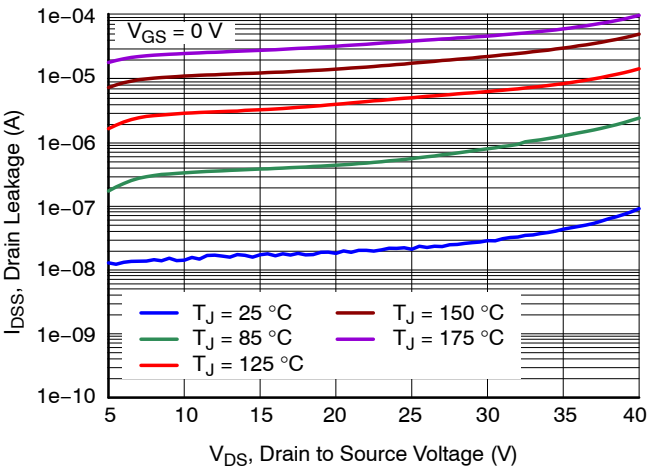


Figure 6. Drain to Source Voltage vs Drain Leakage

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TYPICAL CHARACTERISTICS (Continued)

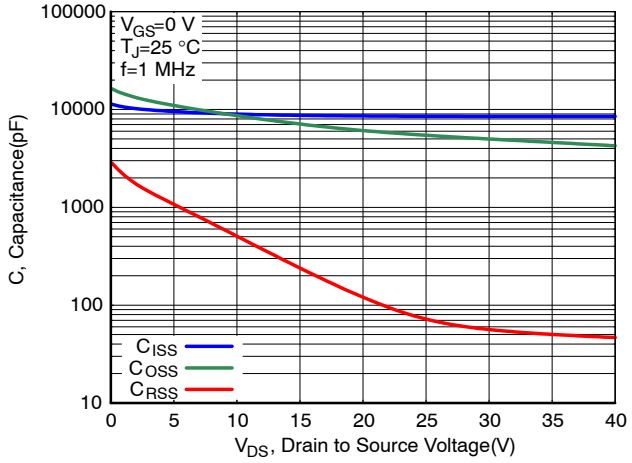


Figure 7. Capacitance Characteristics

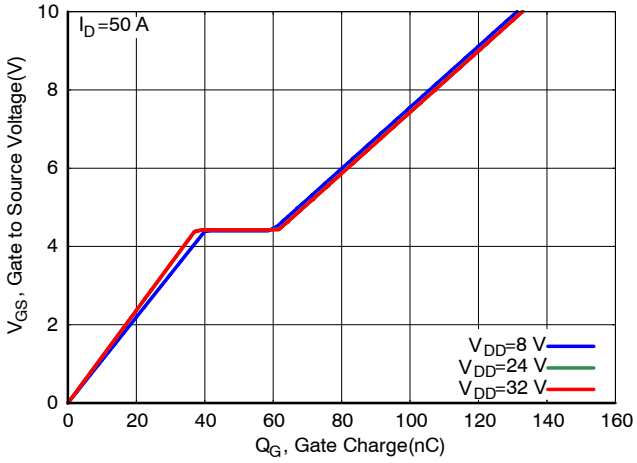


Figure 8. Gate Charge Characteristics

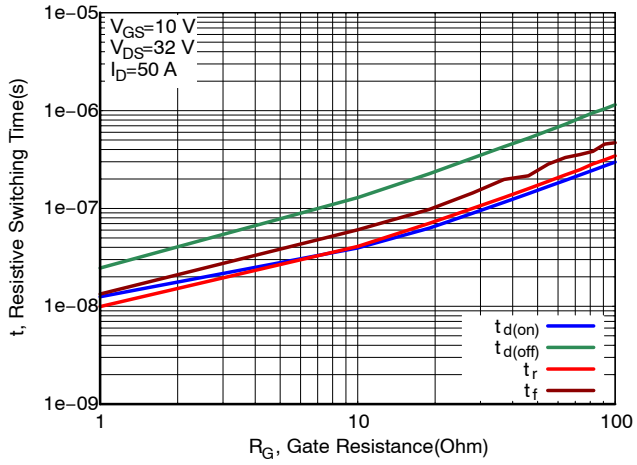


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

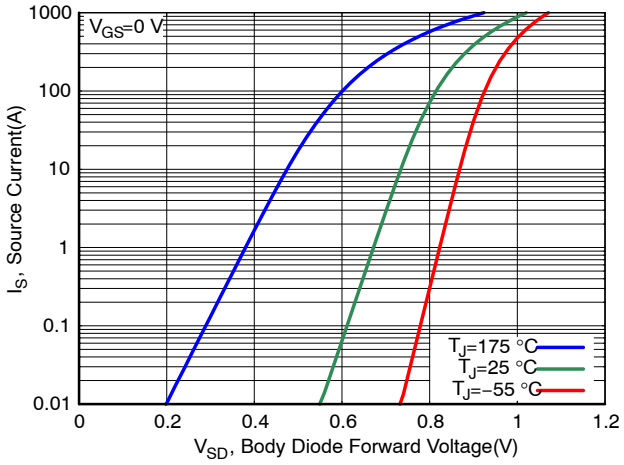


Figure 10. Diode Forward Characteristics

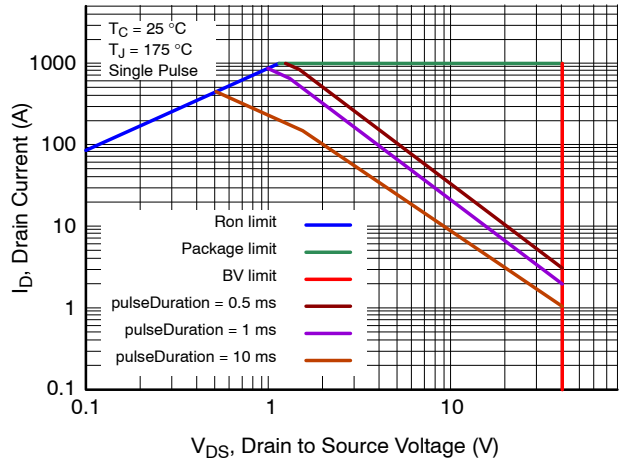


Figure 11. Safe Operating Area (SOA)

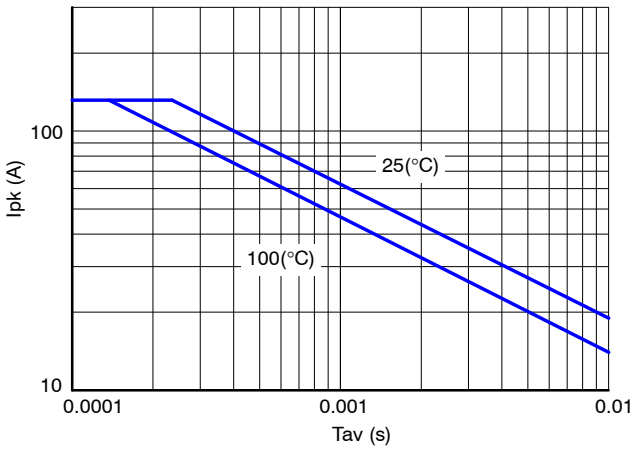


Figure 12. Avalanche Current vs. Pulse Time (UIS)

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TYPICAL CHARACTERISTICS (Continued)

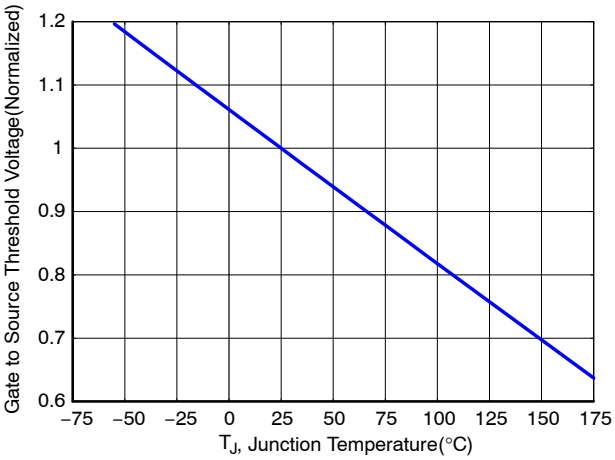


Figure 13. Gate Threshold Voltage vs. Junction Temperature

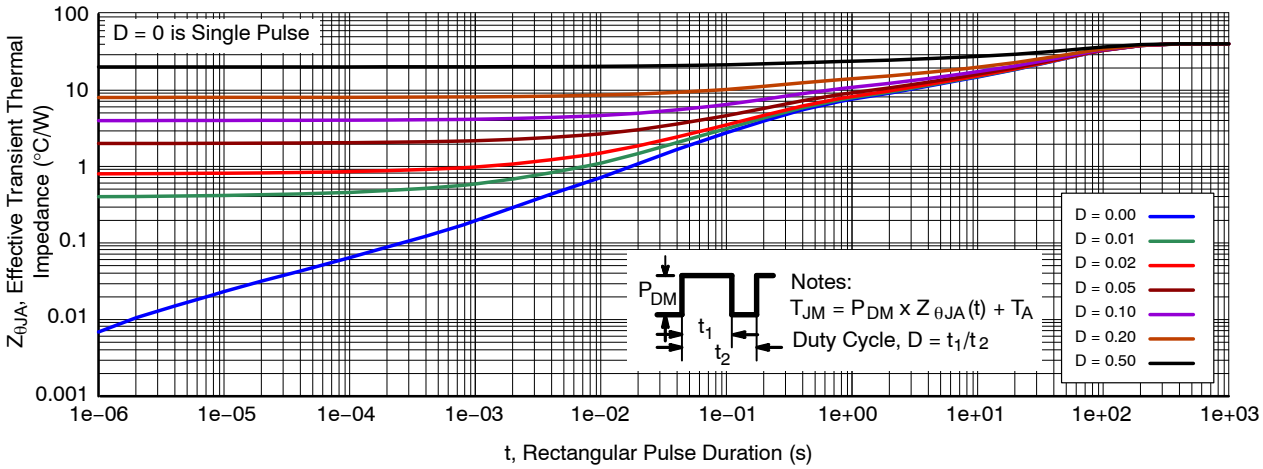


Figure 14. Thermal Response

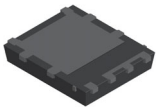
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REVISION HISTORY

Revision	Description of Changes	Date
4	Typical values of parameters t_{RR}, t_a, t_b and Q_{RR} updated in the Electrical Characteristics table.	10/26/2026

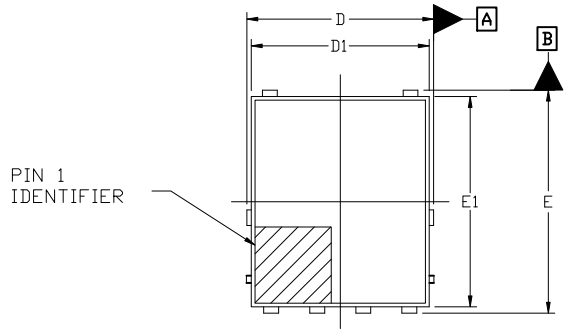
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

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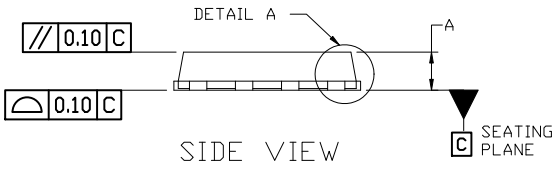


DFNW5 5x6, FULL−CUT SO8FL WF
CASE 507BD
ISSUE O

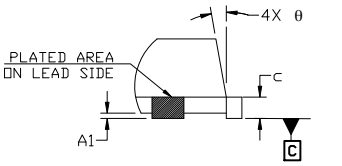
DATE 13 APR 2021



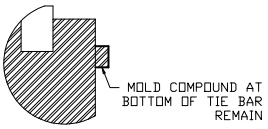
TOP VIEW



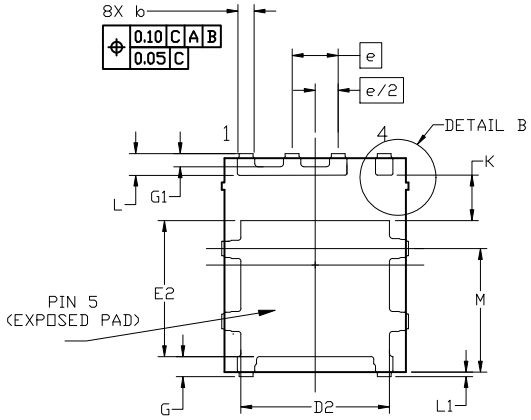
SIDE VIEW



DETAIL A



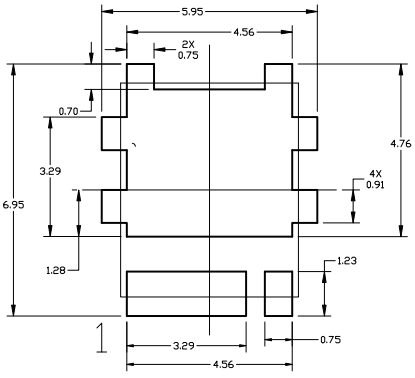
DETAIL B



BOTTOM VIEW

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
4. THIS PACKAGE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

	MILLIMETERS		
DIM	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0.00	---	0.05
b	0.33	0.41	0.51
c	0.23	0.28	0.33
D	5.00	5.15	5.30
D1	4.80	5.00	5.20
D2	3.90	4.10	4.30
E	6.00	6.15	6.30
E1	5.70	5.90	6.10
E2	3.55	3.75	3.95
e	1.27 BSC		
G	0.50	0.55	0.70
G1	0.26	0.36	0.46
k	1.10	1.25	1.40
L	0.50	0.60	0.70
L1	0.150 REF		
M	3.00	3.40	3.80
θ	0°	---	12°



RECOMMENDED
MOUNTING FOOTPRINT

* For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
ZZ = Assembly Lot

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**DFNW5 5x6, FULL−CUT SO8FL WF**	**PAGE 1 OF 1**

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Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

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